

TDS:EMIC

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電源管理



顯示驅動



二三極管



LDO穩壓器



觸摸芯片



MOS管



運算放大器



存儲芯片



MCU



串口通信

SS8550 Y2

產品規格說明書

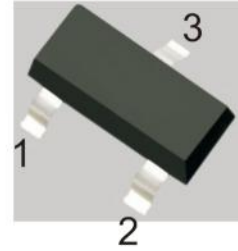
SS8550 Y2

PNP TRANSISTOR

FEATURES

- High Collector Current
- Complementary to SS8050

SOT-23



1.BASE
2.EMITTER
3.COLLECTOR

MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector–Base Voltage	V_{CBO}	-40	V
Collector–Emitter Voltage	V_{CEO}	-25	V
Emitter–Base Voltage	V_{EBO}	-5	V
Collector Current — Continuous	I_C	-1.5	A
Collector Dissipation	P_C	200	mW
Thermal Resistance From Junction To Ambient	R_{thJA}	625	°C/W
Operation Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	°C

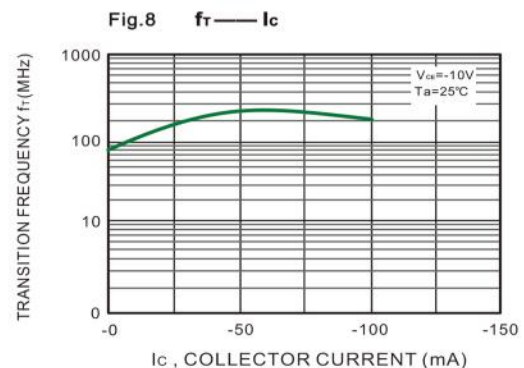
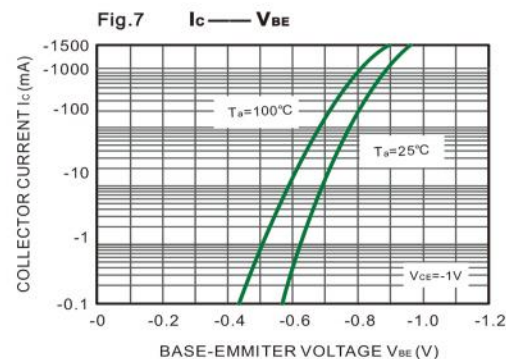
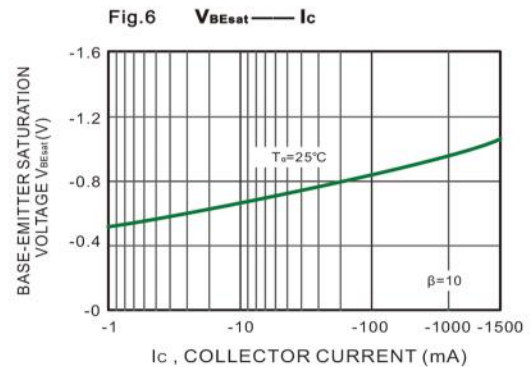
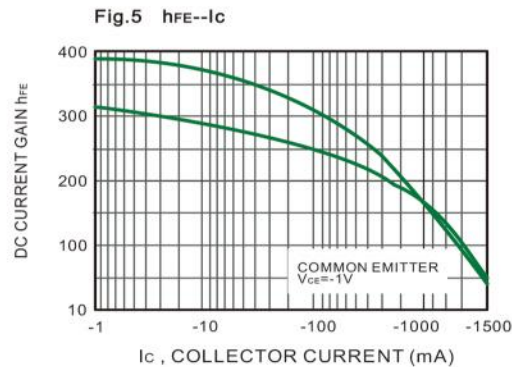
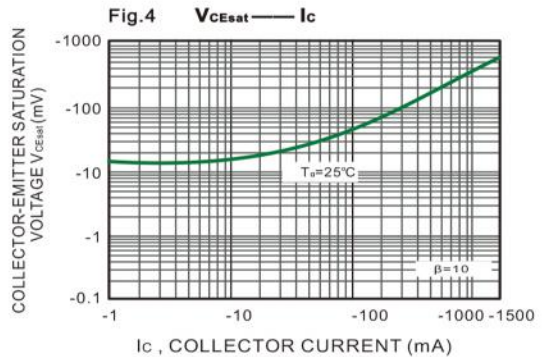
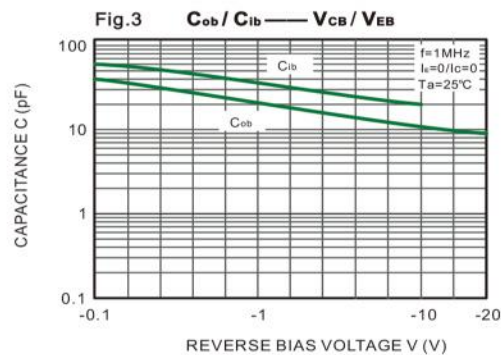
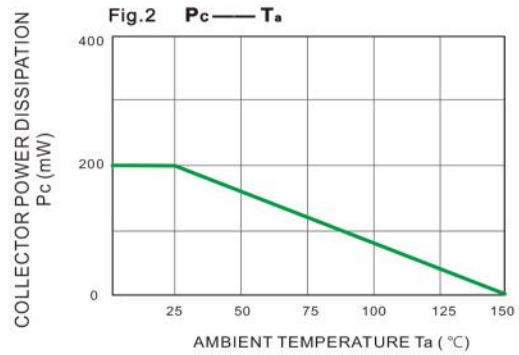
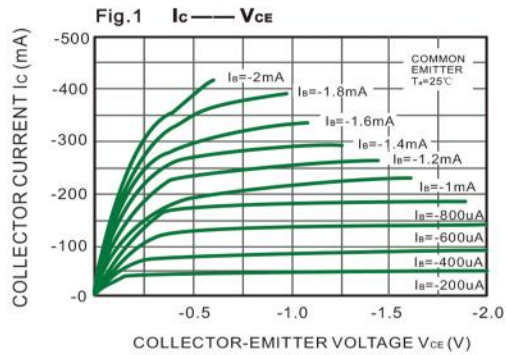
ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted.)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -100\mu A, I_E = 0$	-40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -0.1\text{ mA}, I_B = 0$	-25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -100\mu A, I_C = 0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB} = -40V, I_E = 0$			-0.1	μA
Collector cut-off current	I_{CEO}	$V_{CE} = -20V, I_B = 0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5V, I_C = 0$			-0.1	μA
DC current gain	h_{FE1}	$V_{CE} = -1V, I_C = -100mA$	120		400	
	h_{FE2}	$V_{CE} = -1V, I_C = -800mA$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -800mA, I_B = -80mA$			-0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -800mA, I_B = -80mA$			-1.2	V
Base-emitter voltage	V_{BE}	$V_{BE} = -1V, I_C = -10mA$			-1	V
Transition frequency	f_T	$V_{CE} = -10V, I_C = -50mA, f = 30MHz$	100			MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1MHz$			20	

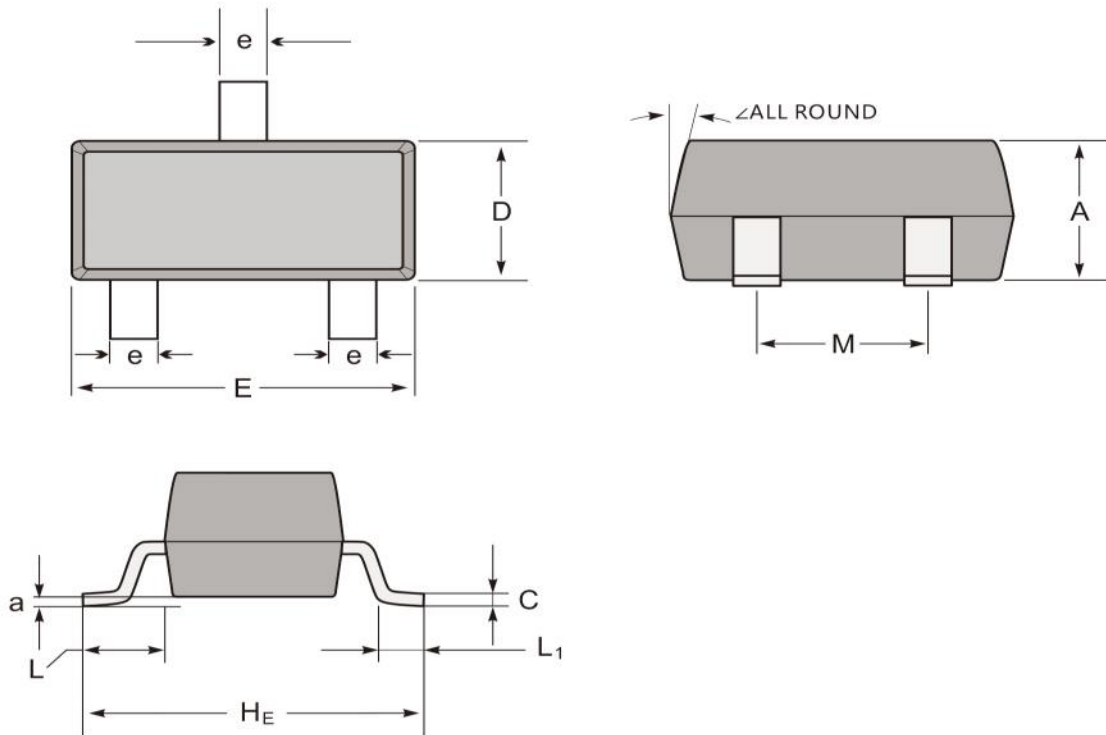
CLASSIFICATION OF $h_{FE(1)}$

RANK	L	H	J
RANGE	120-200	200-350	300-400
MARKING	Y2		

TYPICAL CHARACTERISTICS



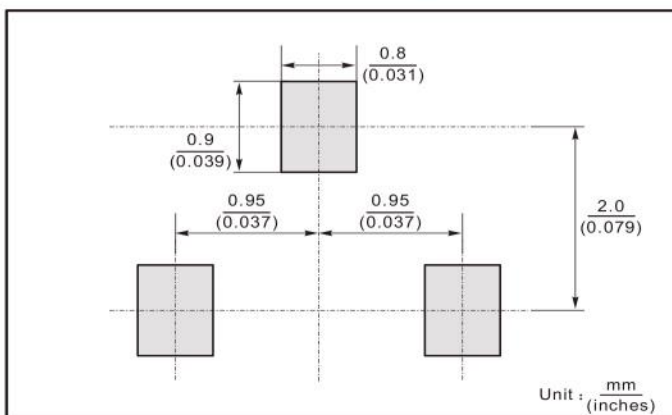
SOT-23 Package Outline Dimensions



SOT-23 mechanical data

UNIT		A	C	D	E	HE	e	M	L	L ₁	a	∠
mm	max	1.1	0.15	1.4	3.0	2.6	0.5	1.95	0.55 (ref)	0.36 (ref)	0.0	12°
	min	0.9	0.08	1.2	2.8	2.2	0.3	1.7			0.15	
mil	max	43	6	55	118	102	20	77	22 (ref)	14 (ref)	0.0	
	min	35	3	47	110	87	12	67			6	

The recommended mounting pad size

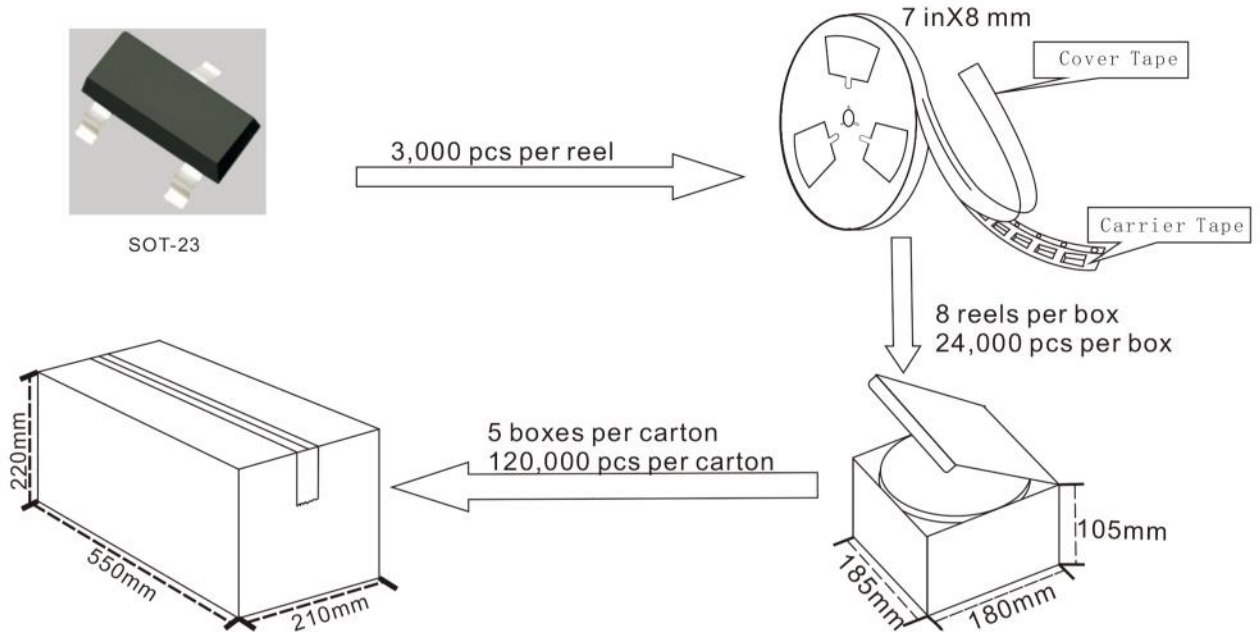


Marking

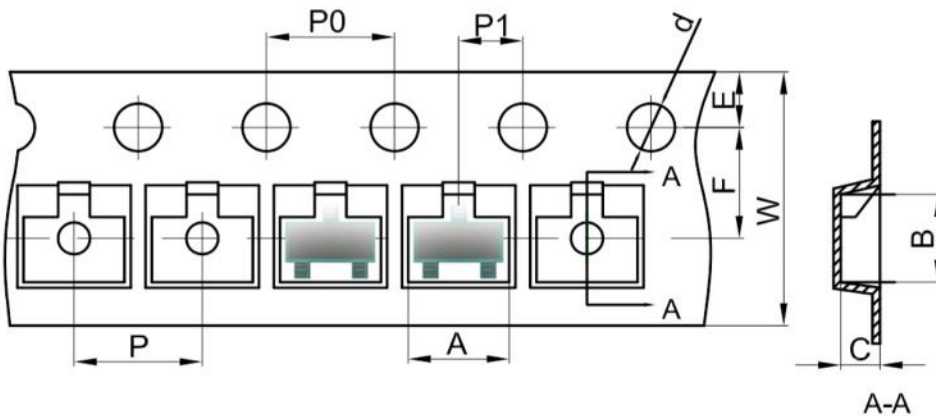
Type number	Marking code
SS8550	Y2

SOT-23 Packing

1. The method of packaging and dimension are shown as below figure. (Dimension in mm)



SOT-23 Embossed Carrier Tape



Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer

